ELM854xx CMOS Dual operational amplifier

■General description

ELM854xx is low power consumption CMOS dual OP-AMP with wide range of common mode signal input voltage and push-pull output stage. With 1.2V single power supply, ELM854xx makes it easy to design power circuit. ELM854xx is suitable for circuit of portable equipments which require low power consumption or single power.

■Features

- Single supply operation
- Low voltage operation　　　　　 : 1.2V≤Vdd≤6.0V
- Low current consumption　　　　 : Typ. 300μA
  (Vdd=3.0V, 2Amp. units total)
- Common-mode input voltage range : Vss to Vdd-0.3V (Vdd=1.5V)
  Vss to Vdd-0.1V (Vdd=3.0V)
- Output stage　　　　　　　　　 : Push-pull
- Unity gain bandwidth　　　　　　 : Typ. 1MHz (Vdd=1.5V)
  Typ. 0.8MHz (Vdd=3.0V)
- Package　　　　　　　　　　　 : SOP-8, TSSOP-8

■Application

- Battery-operated devices
- Micropower signal process
- Low voltage analog circuit

■Maximum absolute ratings

Parameter	Symbol	Limit	Unit
Power supply voltage	Vdd	10	V
Input voltage	Vin	Vss-0.3 to Vdd+0.3	V
Differential input voltage	Vid	Vdd-Vss	V
Output voltage	Vout	Vss-0.3 to Vdd+0.3	V
Output short circuit		Continuous	Sec.
Power dissipation	Pd	300	mW
Operating temperature	Top	-20 to +70	°C
Storage temperature	Tstg	-55 to +125	°C

■Selection guide

ELM854xx-x

Symbol		
a, b	Package	AA : SOP-8 BB : TSSOP-8
c	Taping direction	S : Refer to PKG file N : Refer to PKG file

ELM854 x x - x
　　　　 ↑ ↑　↑
　　　　 a b　 c

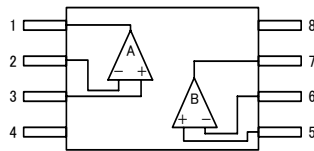# ELM854xx CMOS Dual operational amplifier
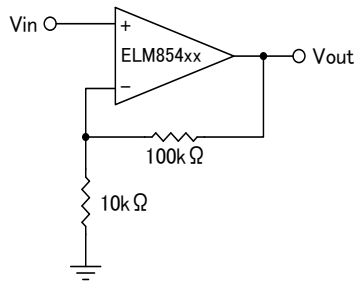
■Pin configuration
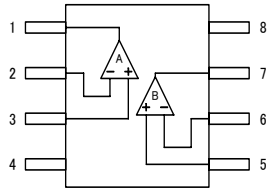
SOP-8 (TOP VIEW)   TSSOP-8 (TOP VIEW)

Pin No.	Pin name	Pin No.	Pin name
1	OUTA	5	IN+B
2	IN-A	6	IN-B
3	IN+A	7	OUTB
4	VSS	8	VDD

■Standard circuit

Vin ○ — +
ELM854xx — ○ Vout
−
100kΩ
10kΩ

■Electrical characteristics(Vdd=1.5V)

Vss=0V, Top=25°C

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input offset voltage	Vio	Vin+=Vdd/2, Unity gain follower			±6	mV
Input bias current	Iib				1.0	nA
Common-mode input voltage range	Vcmr	For CMRR≥45dB	0.00		1.20	V
Maximum output voltage swing	Vouts	Vid=100mV, RL=10kΩ to Vss	1.40			V
Large-signal voltage gain	Avd	RL=10kΩ to Vss		85		dB
Common-mode rejection ratio	CMRR	RL=10kΩ to Vss		65		dB
Supply voltage rejection ratio	PSRR	RL=10kΩ to Vss Vdd=1.35V to 6.0V		85		dB
Current consumption	Iss	Vin+=Vdd/2, Unity gain follower		270	400	μA
Unity gain bandwidth	GBW			1.0		MHz
Slew rate	SR	RL=100kΩ, CL=20pF	0.55	0.85		V/μs

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ELM854xx CMOS Dual operational amplifier

■Electrical characteristics(Vdd=3.0V)

Vss=0V, Top=25°C

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input offset voltage	Vio	Vin+=Vdd/2, Unity gain follower			±6	mV
Input bias current	Iib				1.0	nA
Common-mode input voltage range	Vcmr	For CMRR≥45dB	0.00		2.90	V
Maximum output voltage swing	Vouts	Vid=100mV, RL=10kΩ to Vss	2.90			V
Large-signal voltage gain	Avd	RL=10kΩ to Vss		90		dB
Common-mode rejection ratio	CMRR	RL=10kΩ to Vss		70		dB
Supply voltage rejection ratio	PSRR	RL=10kΩ to Vss Vdd=2.7V to 6.0V		90		dB
Current consumption	Iss	Vin+=Vdd/2, Unity gain follower		300	450	μA
Unity gain bandwidth	GBW			0.8		MHz
Slew rate	SR	RL=100kΩ, CL=20pF	0.40	0.65		V/μs

■Marking

SOP-8   TSSOP-8

ELM
854AA
a b c

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854abc
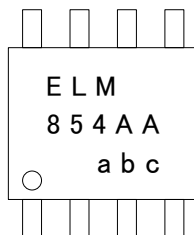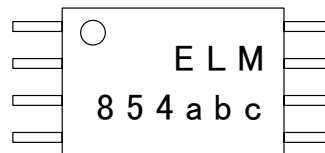
No.	Mark	Content
a	0 to 9	Last numeral of A.D.
b	A to M (excepted I)	Assembly month
c	0 to 9	Lot No.

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■Note

1) Common-mode input voltage range

ELM854xx common mode input voltage range is fixed under the condition of CMRR≥45dB; ELM854xx is able to accept the input above its specification if the degradation of CMRR is not considered. Even if the input voltage exceeds either positive or negative power voltage, troubles such as reverse of output will not occur.

As maximum absolute rating, the input voltage is possible within (Vss-0.3)V to (Vdd+0.3)V.

2) Operation from single power source

ELM854xx is designed to be most suitable for single power source; therefore, ELM854xx is able to share power supply with logic circuit one. Meanwhile, ELM832BW can also operate from double power sources. To protect power supplies of ELM854xx and logic circuit from noise, please separate wire from power supply and use decoupling (bypass) capacitor. Using the capacitor can improve PSRR characteristics, especially on 10kHz to 100kHz or more.

3) Feedback

When OP-AMP circuit is used with feedback resistor, oscillation may happen in the circuit with loop-gain like unity gain follower.

a) When large feedback resistance is used, the phase margin is decreased by its combination with the parasitic capacitance of the input part of OP-AMP. In this situation, please connect small capacitor parallelly with feedback resistor as shown in fig-1.

b) For capacitive load, external resistor in series connection will be effective as shown in fig-2. (R=300 to 500Ω)

c) Being used as an unity gain follow, ELM854xx is able to drive capacitive load of 100pF directly without oscillation.
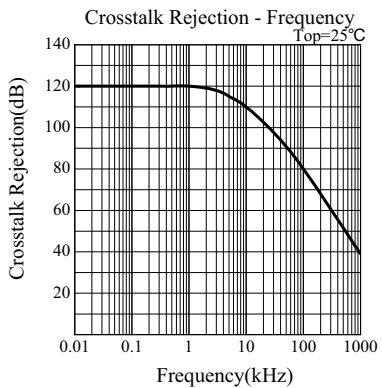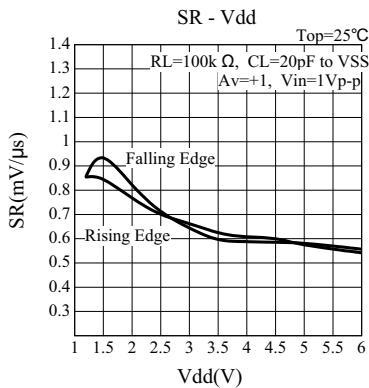

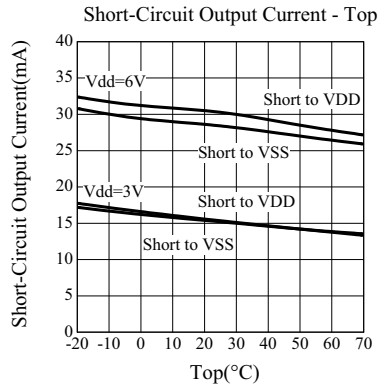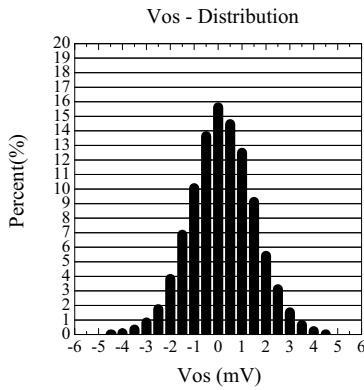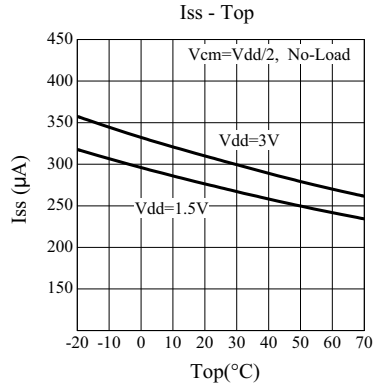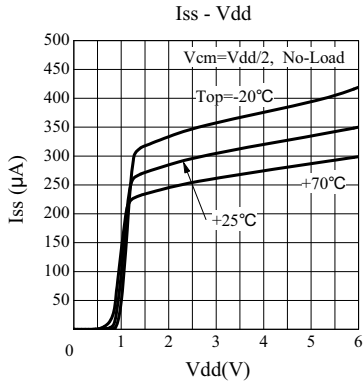a) fig-1   b) fig-2
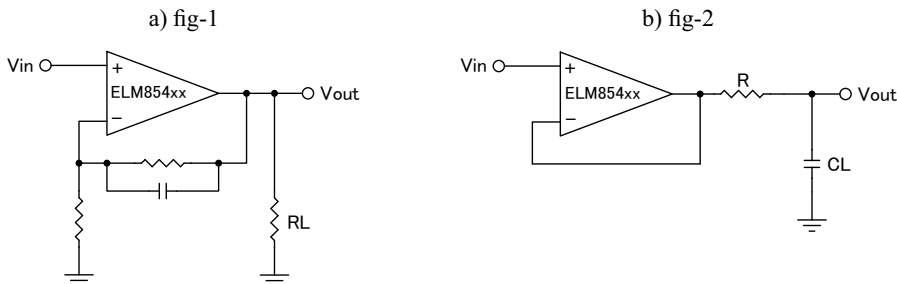
4) Unused Amplifier

Two amplifiers will consume power even if only one amplifier is used.

In order to minimize power consumption by the unused amplifier, ELM recommends to connect this amplifier as voltage follower circuit and the input terminal (IN+) to Vdd.
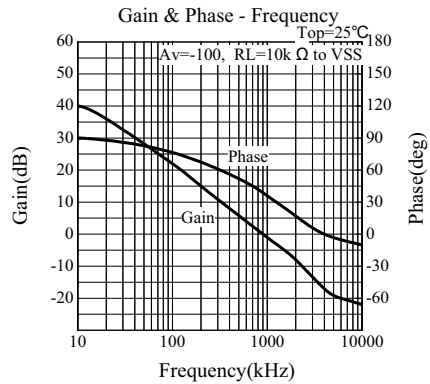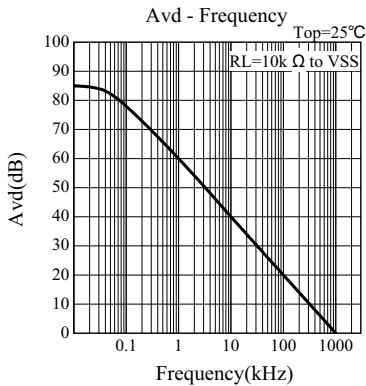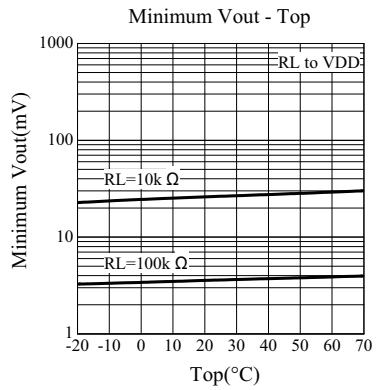
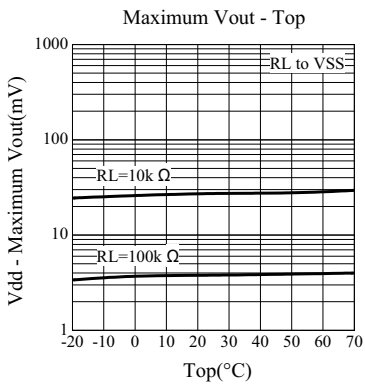■Typical characteristics

Iss - Vdd

Vcm=Vdd/2, No-Load
Top=-20℃
+70℃
+25℃

Iss (μA) vs Vdd(V)

Iss - Top

Vcm=Vdd/2, No-Load
Vdd=3V
Vdd=1.5V

Iss (μA) vs Top(°C)

Vos - Distribution

Percent(%) vs Vos (mV)

Short-Circuit Output Current - Top

Vdd=6V
Short to VDD
Short to VSS
Vdd=3V
Short to VDD
Short to VSS

Short-Circuit Output Current(mA) vs Top(°C)

SR - Vdd

Top=25℃
RL=100kΩ, CL=20pF to VSS
Av=+1, Vin=1Vp-p
Falling Edge
Rising Edge

SR(mV/μs) vs Vdd(V)

Crosstalk Rejection - Frequency

Top=25℃

Crosstalk Rejection(dB) vs Frequency(kHz)

■1.5V Performance

Isource - Vout
Top=25℃

Isource(mA) vs Vout(V)
Vdd=1.5V

Isink - Vout
Top=25℃

Isink(mA) vs Vout(V)
Vdd=1.5V

Maximum Vout - Top

Vdd - Maximum Vout(mV) vs Top(°C)
RL to VSS
RL=10k Ω
RL=100k Ω

Minimum Vout - Top

Minimum Vout(mV) vs Top(°C)
RL to VDD
RL=10k Ω
RL=100k Ω

Avd - Frequency
Top=25℃
RL=10k Ω to VSS

Avd(dB) vs Frequency(kHz)

Gain & Phase - Frequency
Top=25℃
Av=-100, RL=10k Ω to VSS

Gain(dB) / Phase(deg) vs Frequency(kHz)
Phase
Gain

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CMRR - Frequency

Top=25℃

Vcm=Vdd/2, RL to VSS

RL=100k Ω

RL=10k Ω

CMRR(dB)

Frequency(kHz)

CMRR - Vcm

Top=25℃

RL=10k Ω to VSS

CMRR(dB)

Vcm(V)

PSRR - Frequency

Top=25℃

PSRR(dB)

Frequency(kHz)

CMRR, PSRR - Top

RL=10k Ω to VSS

PSRR

CMRR

CMRR, PSRR(dB)

Top(°C)

SR - Top

RL=100k Ω, CL=20pF to VSS

Av=+1, Vin=1Vp-p

Rising Edge

Falling Edge

SR(mV/μs)

Top(°C)

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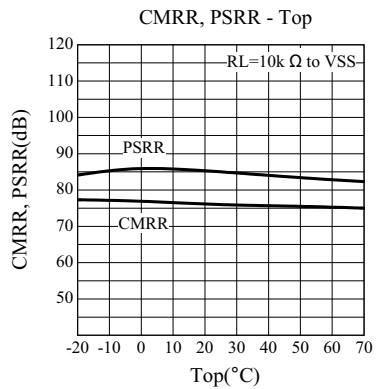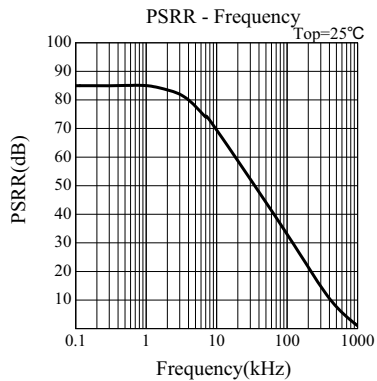TECHNOLOGY

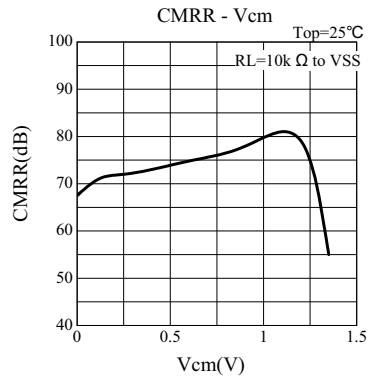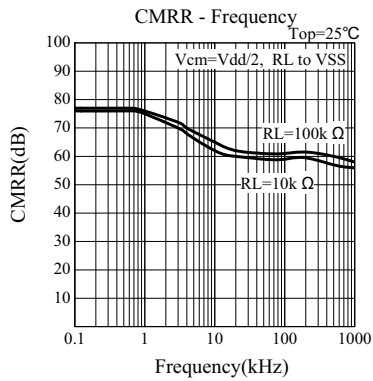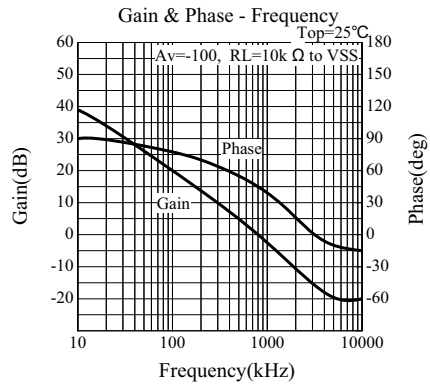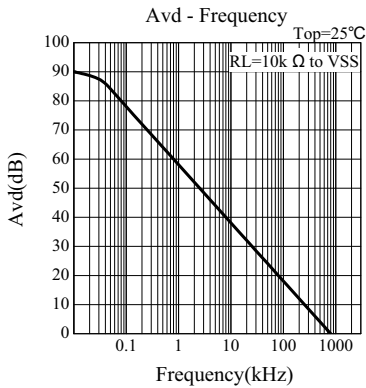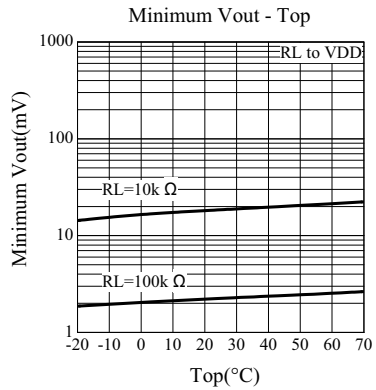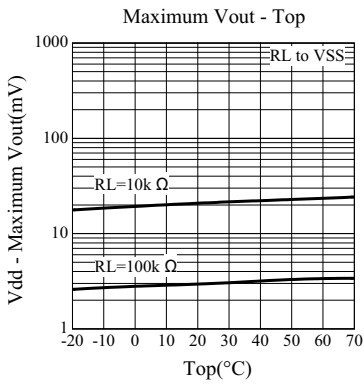# ELM854xx CMOS Dual operational amplifier

■3.0V Performance

Isource - Vout
Top=25℃

Vdd=3V

Isource(mA)

Vout(V)

Isink - Vout
Top=25℃

Vdd=3V

Isink(mA)

Vout(V)

Maximum Vout - Top

RL to VSS

Vdd - Maximum Vout(mV)

RL=10k Ω

RL=100k Ω

Top(°C)

Minimum Vout - Top

RL to VDD

Minimum Vout(mV)

RL=10k Ω

RL=100k Ω

Top(°C)

Avd - Frequency
Top=25℃
RL=10k Ω to VSS

Avd(dB)

Frequency(kHz)

Gain & Phase - Frequency
Top=25℃
Av=-100, RL=10k Ω to VSS

Gain(dB)

Phase

Gain

Phase(deg)

Frequency(kHz)

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CMRR - Frequency
Top=25℃
Vcm=Vdd/2, RL to VSS

RL=100k Ω

RL=10k Ω

CMRR(dB) vs Frequency(kHz)

CMRR - Vcm
Top=25℃
RL=10k Ω to VSS

CMRR(dB) vs Vcm(V)

PSRR - Frequency
Top=25℃

PSRR(dB) vs Frequency(kHz)

CMRR, PSRR - Top
RL=10k Ω to VSS

PSRR

CMRR

CMRR, PSRR(dB) vs Top(°C)

SR - Top
RL=100k Ω, CL=20pF to VSS
Av=+1, Vin=1Vp-p

Rising Edge

Falling Edge

SR(mV/µs) vs Top(°C)